

ESDA ONLINE ACADEMY

Our online classes are designed into four main disciplines or subject matter noted as the starting letters in the class number; FC-Factory Control, Manufacturing classes; DD-Device Design classes; DT-Device Stress Testing classes; and GP-General Practitioner classes.

We offer three certification programs which are: Program Manager (PrM), Device Design (DD), and Device Stress Testing (DT). Our online academy training form provides a table that lists subject matter letters in the class “#” column and the certification letters in the “cert” column.

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ESDA ONLINE ACADEMY

RECORDED ON-DEMAND COURSES

✓	#	Course Title	Cert.	#Credits
		3D Integration with Through-Silicon Via (TSV)		1
	FC363	Advanced ESD/EMI Auditing Techniques		1
	DT300	Advanced HBM – Dealing with Tester Parasitics, High Pin Count and Two Pin Testing	DT	1
	DT200	CDM Testing Essentials	DT	1
	FC171	Changes to ANSI/ESD S20.20 from the 2007 version to the 2014 version		1
	GP230	Charged Board Events: A Growing Industry Concern		1
	DD200	Charged Device Model Phenomena, Design and Modeling	DD	3
	FC110	Cleanroom Considerations for the Program Manager	PrM	3
	FC211	Compliance Verification: Pitfalls of Auditing		1
	FC180	Controlling ESD in Automated Equipment by Proper Grounding		1
	FC241	Developing a Compliance Verification Program		1
	DT202	Device Stress Testing Standards Update	DT-R	1
	FC220	Device Technology & Failure for the Program Manager	PrM	3
	DT230	Device Testing Correlation to Root Cause Failure Analysis		1
	FC261	Electric Fields: Practical Considerations		1
	FC360	Electrical Overstress (EOS) in Manufacturing and Test		3
	FC260	Electrostatic Attraction		1
	FC380	Electrostatic Calculations for the Program Manager (4 Hrs)	PrM	3
	DD104	Electrostatic Discharge Effects In Integrated Circuit Technologies		1
	GP250	EOS-A Big Challenge in Today's Handling of Customer Rejects		1
		EOS: A New Focus		1
	DD110	ESD from Basics to Advanced Protection Design	DD	
	DT140	ESD Fundamentals I for Stress Testing	DT	1
	DT141	ESD Fundamentals II for Stress Testing	DT	1
	GP331	ESD Problem Solving		1
	DD201	ESD Protection and I/O Design		3
	FC210	ESD Standards Overview for the Program Manager	PrM	3

✓	#	Course Title	Cert.	#Credits
	DT220	ESD Test Simplification with Approved Sampling Methods in HBM	DT-E	1
	DT143	Essentials for Controlling the ESD Work Area	DT	1
	DT142	Fundamentals of Failure Analysis	DT	1
	DT130	Fundamentals of System Level Testing	DT-E	1
	FC231	Grounding in an Electrostatic Protected Area Chinese		
	FC231	Grounding in an Electrostatic Protected Area		1
	DT100	HBM Testing Essentials	DT	1
	DT211	High Speed Digital Oscilloscope Fundamentals	DT	1
	FC181	Highlights and key concepts of Footwear/Flooring Standards		1
	FC181	Highlights and key concepts of Footwear/Flooring Standards Korean		1
	FC181	Highlights and key concepts of Footwear/Flooring Standards THAI		1
	DT131	HMM – System Level Testing of Components	DT-E	1
	DD103	Integrated Circuit ESD Fundamentals		3
	DD340	Integrated ESD Device and Board Level Design		2
	FC120	Ionization Issues and Answers for the Program Manager	PrM	3
	DD112	Latch-up Fundamentals	DD	1
	DT201	Latch-up Testing and Troubleshooting	DT-E	1
	DD102	On-Chip Protection in RF Technologies	DD	1
	GP330	Overview on Efficient and Reliable System-Level ESD		1
	FC200	Packaging Principles for the PrM	PrM	3
	DD222	Practical Aspects of Latch-Up for Low Voltage CMOS: Design Rules, Layout Floor Planning, and Test		1
	DD132 FC132	Susceptibility Testing of Devices and Systems		1
	DD130 FC130	System Level ESD/EMI: Testing IEC & Other Standards	DD	3
	FC140	System Level for the Program Manager	PrM	3
	DD117	TCAD Fundamentals		1
	DD205	TCAD Methodologies for Industrial ESD Design		1
	DD210	TLP Fundamentals–Understanding the Equipment Options	DT-E	1
	FC361	Ultra-sensitive (Class 0) Devices: ESD Controls and Auditing Measurements		3
	GP241	Ultra-Sensitivity Trends and CDM		1
	FC122	Use of Digital Sampling Oscilloscope for ESD Measurement		3
	DT212	VF-TLP, An Introduction to Capabilities and Applications	DT-E	1

Certification information can be found at <https://www.esda.org/certification/>

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ESDA ONLINE ACADEMY COURSE CATALOG

COURSE ABSTRACTS

3D Integration with Through-Silicon Via (TSV) (1 Hour)

Instructor: Souvick Mitra

3D integration with through-silicon via (TSV) is a promising candidate to perform integration options with chip and/or wafer level stacking are emerging as the next generation of technologies that will continue to drive performance, power reduction and form factor shrinkage [1][2]. Some key advantages of the 3D integrated circuits are reduction of interconnect length which leads to improved interconnect delay, higher bandwidth/lower power, rapid access to memory, wide range of heterogeneous integration possibility, smaller Form-Factor etc. TSV fabrication is the key technology to permit communications between various strata of the 3D integration system. Hence understanding of TSV fabrication steps, such as etching, isolation, metallization processes, and related failure modes is important for 3D ICs. Per ITRS Roadmap [3], ESD protection of the core logic devices is identified as a critical challenge for the 3D process sequence. Hence proper understanding of ESD protection levels is also required for 3D integrated chip-to-chip signals with the goal of minimizing impact (area and latency) of 3D chip-to-chip connections. All such aspects and multiple other work related to 3D integration and ESD will be discussed and reviewed in this tutorial.

Advanced ESD/EMI Auditing Techniques (1 Hour) FC363

Instructor: Al Wallash

In order to solve today's ESD problems, ESD auditing must provide data on not only the static charge and voltage on tooling and devices, but also the transient voltage, current and electromagnetic field interference (EMI) up to at least 1 GHz. This practical course will teach how to use a variety of charge, current, voltage and E-field probes to understand the ESD/EMI threats during processing of ESD sensitive devices.

Advanced HBM – Dealing with Tester Parasitics, High Pin Count and Two Pin Testing (1 Hour) DT300

Instructor: Scott Ward

Certification: DT

This tutorial provides an overview of the joint HBM standard by the ESDA and JEDEC which introduces numerous options to set up the test plan for HBM qualification. The options include high pin count devices, reducing relay capacitance from the tester and two pin testing. There was a need to explain these options in detail and a user guide has also been released to provide further guidance in these tests. This tutorial will attempt to cover the user guide and will give examples of setting up the different tests plans that utilize the options outlined in the standard.

CDM Testing Essentials (1 Hour) DT200

Instructor: Alan Righter

Certification: DT

This tutorial will give students the fundamental information required to quickly learn the CDM testing method on commercial CDM test equipment and the associated oscilloscope / metrology chain information needed to capture and interpret CDM waveforms. Additional information on CDM testing standards and their hardware differences, package effects on the CDM waveforms and package limitations will be covered. Students will also be introduced to the background information needed in understanding CDM failure modes along with test program output failure types needed to understand the effects of CDM testing.

Changes to ANSI/ESD S20.20 from the 2007 version to the 2014 version (1 Hour) FC171

Instructor: John Kinnear

This presentation will describe the changes to ANSI/ESD S20.20. The reasoning behind the changes will be addressed and questions will be taken from the audience. The actual presentation will be 30 to 35 minutes with time at the end for open discussion.

Charged Board Events: A Growing Industry Concern (1 Hour) GP230

Instructor: Terry Welsher

A charged board stores much more energy than a device (IC) because its capacitance is many times larger. In fact, the charge (energy) transferred in the event is so large that it can cause EOS-like failures to the components on the board. In this seminar, this board-level ESD event will be compared with the component level CDM ESD event. The waveforms from both ESD events will be compared and it will be shown that for the same voltage, the current in the board-level ESD event will be much higher than that from the chip-level ESD event. A summary of literature and industry data will be given. It is suggested that failure analysts give stronger consideration to these types of board level events before assigning an EOS diagnosis to the failure. This will support more effective root cause analysis and prevention of these failures.

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Charged Device Model Phenomena, Design and Modeling (3 Hours) DD200

Instructors: Melanie Etherton, Mike Chaine

Certification: DD

This course teaches basic ESD circuit design concepts and ideas required to design ESD protection for Charge Device Model ESD tests. The course covers a brief history of CDM ESD development, charge and discharge physics, characterization methods, CDM failures mechanisms, and CDM design-in strategies.

CDM ESD circuit design approaches and simulation setups for CDM failure debugging are presented in this tutorial on the basis of case studies. Insight into CDM circuit simulation requirements and physical aspects of the CDM ESD phenomenon that are important for reproducing the event with circuit simulation will be taught and modeling approaches for CDM specific device physical effects necessary for accurate circuit simulation will be introduced. This course also teaches methods for simplified CDM circuit simulations where detailed information is either not available or too complex to simulate.

The course focuses on what type of circuits fail during a CDM discharge event and teaches the different types of ESD design circuit strategies that can be applied to protect those circuits. This class covers basic to advanced topics for CDM ESD design, but the student is assumed to already have a basic understanding of the CDM test method.

Cleanroom Considerations for the Program Manager (3 Hours) FC110

Instructor: Christopher Long

Certification: PrM

Cleanrooms and clean environments are enabling technologies required for the manufacturing of many products that have exacting contamination control requirements in order to achieve defined yield and reliability targets. Clean manufacturing is required in the semiconductor, hard disk drive, flat panel display, and pharmaceutical industries, to name a few. Requirements of cleanroom and clean environments, and tooling therein, result in low humidity levels, low surface contamination levels, use of process-required insulators, and a lack of natural ions in the controlled environment. These factors can contribute to the development of elevated static charge levels in close proximity to sensitive products, presenting both a contamination and electrostatic discharge exposure.

This tutorial will provide a detailed review of the following concepts:

- Cleanroom and clean environment function
- Airborne particle classification standards
- Cleanroom compliance monitoring test methodologies
- Electrostatic attraction relation to airborne and surfacecontamination
- Electrostatic discharge concerns
- Cleanroom static charge generation challenges and control methodologies
- In addition, several case studies of static charge control issues in clean environments will be presented.

Compliance Verification: Pitfalls of Auditing (1 Hour) FC211

Instructor: Ginger Hansel

Accurate data is the foundation of effective ESD Program Management. Therefore, it's important to have confidence in the measurements. Choosing the correct type of equipment for each measurement is also important and not always obvious. The class will cover the correct use of static locators, resistance meters, event detectors, and how to use ionizers effectively. We will discuss the various pitfalls of commonly used instruments, and the invalid test results that can result. For instance, static locators can yield totally invalid readings when used incorrectly due to voltage suppression. What you learn will help you avoid frequently encountered auditing problems, and improve your compliance verification program.

Controlling ESD in Automated Equipment by Proper Grounding (1 Hour) FC180

Instructor: Donn Bellmore

This course will focus on the grounding and material requirements of ESD Controls in Automated Handling Equipment (AHE) for prevention of CDM and MM type damage to ESD sensitive devices. Design methods and material selections that provide effective ground paths through the assembly will be introduced. Test methods used to qualify the design will be discussed. Students will also become familiar with different types of plating and practices to provide effective designs.

Developing a Compliance Verification Program (1 Hour) FC241

Instructor: John Kinnear

Compliance verification is one of the required elements in the ANSI/ESD S20.20 standard. Without periodic verification of the ESD materials used within an Electrostatic Protected Area (EPA) programs can degrade over time. This course will cover some of the items that need to be considered for a successful compliance verification program.

Topics covered in this program include,

- What is a compliance verification program?
- What is the difference between product qualification and compliance verification?
- How does the ESD program manager determine the frequency of testing?

As part of the course, common ESD control items will be covered and how to do the testing efficiently and to meet the requirements of ANSI/ESD S20.20 and TR53. Questions can be submitted in advance to be answered as part of the course.

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Device Stress Testing Standards Update (1 Hour) DT202

Instructor: Alan Righter

Certification: DT

This tutorial will describe major updates to the HBM and CDM Device Stress Testing Standards. After a brief introduction to both the Joint ESDA/JEDEC HBM and proposed Joint CDM Standards and the motivations for their developments, specific improvements in each standard (relative to their previous separate ESDA and JEDEC standards) will be described. These stress testing method improvements will be supported by test setup and measurement data where appropriate. Examples of the HBM and CDM stress testing procedures (setting up, measurement) using the new updated standards will be given. After taking this course, students will have the basic understanding of the improvements in the Joint HBM and proposed Joint CDM Standards and a basic understanding of how to apply these improvements to existing testers for stress testing.

Device Technology & Failure Analysis for the Program Manager (3 Hour) FC220

Instructor: Terry Welsher

Certification: PrM

This tutorial provides an overview of the device design and fabrication technology of integrated circuits and other potentially ESD-sensitive devices; the basic concepts and techniques used to provide built-in ESD protection; and Failure Analysis (FA) techniques to determine the root causes of failures of device due to ESD. This class does not go into the depth necessary to equip the student to be an ESD Protection Designer or an ESD Failure Analysis Engineer. It does familiarize the student with the terms and concepts of ESD protection and FA to allow the student to interact with and understand the work being done by the Designer or Failure Analyst. After completing this tutorial, the student should be able to understand the basics of device ESD protection design and some of the trade-offs inherent in that process. The student will also become familiar with the commonly used failure analysis techniques and tools used to identify the root cause of an ESD failure. The common ESD Models (HBM, CDM), characteristics of ideal and real-world ESD protection are described. In addition, the broader topic of failure of devices due to more general electrical stresses is introduced. The terms electrical overstress (EOS) and electrically induced physical damage (EIPD) are defined with aim of understanding how ESD failures can be distinguished from other stresses.

Device Testing Correlation to Root Cause Failure Analysis (1 Hour) DT230

Instructor: Leo G. Henry

ESD Device Stress Testing is known to benefit at least three areas: qualifying the product, simulate failures from factory or field, and to improve the design of the product. Three ESD models (HBM, MM and CDM) are used to simulate failures and to differentiate between the different types of ESD failures and also to differentiate the ESD type failures from EOS-type failures. Even though there are no Failure Analysis standards for ESD, there is enough archived data, published data and experience to show correlation exists between the ESD Stress testing types, the physical failure types and the eventual root cause. The type of equipment required to get to the physical failures and see the failures will be emphasized. The class will show how to correlate each ESD model stress testing results to the physical failure type and the physical failure location on the die. A real example will be used to show how the ESD stress testing lead to the root cause of a field failure.

Electrical Overstress (EOS) in Manufacturing and Test (3 Hour) FC360

Instructor: Terry Welsher, Dangelmayer Associates

Electrical overstress (EOS) is a major cause of device failure in manufacturing and in the field. Despite this, there is relatively little information on the sources of EOS and on prevention practices, particularly for the factory. In this tutorial, the fundamentals of device overstress are reviewed. Relationships among device EOS stressing models, such as the Wunsch-Bell curve, are discussed. The causes of EOS and EOS-like events in manufacturing are described and categorized by source and by stress-type. The difficulties in distinguishing between power-induced EOS and high current ESD events such as charged-board events (CBE) and cable discharge events (CDE) are discussed. Case histories, including failure analysis and root cause determination, are presented and the few relevant industry specifications are reviewed.

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Electric Fields: Practical Considerations (1 Hour) FC261

Instructor: David E. Swenson

ANSI/ESD S20.20 requires that process essential insulators with a measured electrical field strength of >2000 volts at 1 inch be kept a minimum of 12 inches from ESD susceptible items. Just what are the practical considerations of this statement? What about electrical fields of 1999 volts at 1 inch? Can items with lower field strength be ignored? Is there a size consideration when it comes to charged objects? If so, what is the size of a charged object that imposes a risk? What is the magnitude of an electrical field that should be of concern in a process?

This tutorial presents information from a recent investigation of electrical field strength that was conducted to support a revision of ANSI/ESD S20.20. The audience should gain a practical perspective of size and distance as related to electrical field strength. Additionally, the audience should be able to relate the information in this tutorial to their own process environments to help estimate the risk of damage to sensitive items that may be grounded within the electrical field from process essential insulators.

Electrostatic Attraction (1 Hour) FC260

Instructor: Carl Newberg

This training will cover the causes and effects of electrostatic attraction (ESA) and the solution to ESA problems in a variety of industries. Electrostatic attraction problems plague industries from photographic to medical and electronics. In the electronics industry alone, electrostatic attraction problems can be found in disk drive assembly, wafer fabrication and PC board assembly. The solutions to these problems can be found by applying a combination of the fundamentals of electrostatics and contamination control. An overview of clean rooms, ionization, materials and the control of static electricity will be presented. Real world problems and their solutions will be discussed using case histories.

- I. Basics of electrostatics
- II. Types of bonding
- III. Physics of electrostatic attraction
- IV. Industrial problems
- V. Solving electrostatic attraction problems
- VI. Case studies

Electrostatic Calculations for the Program Manager (4 Hours) FC380

Instructors: Leo G. Henry, Terry Welscher

Certification: PrM

This tutorial focuses on the basic mathematical formulae, calculations of use to the program manager. The content is at the introductory college pre-calculus and introductory college physics level with emphasis on electrostatics and basic electronics concepts. It is suggested that the student gain some familiarity with these subjects prior to the tutorial. Topics covered include the electrical charge, the electric field and Coulombs law, electric potential, and voltage, decay equations, and definitions and calculation of resistance and capacitance. Basic equations and relationships are explained to enable the application of the fundamental relationships. The fundamental equation, $Q = CV$, is used to explain charge sharing in real world situations. RC decay is discussed as it relates to ESD discharge from humans, devices, wrist straps, and materials and to air ionization. Simple models are used to compare models for various types of ESD (Human-Body Model, Charged Device Model and others) and provide a conceptual understanding of the differences among the calculations for peak current, power, energy, and threshold voltage for a simple device.

Electrostatic Discharge Effects in Integrated Circuit Technologies (1 Hour) DD104

Instructor: Charvaka Duvvury

This course will outline the fundamentals of ESD phenomena and the methods to control the effects of ESD for safe manufacturing of IC devices. The training material will include the nature of ESD transients, their impact on the IC devices, common methods to test for ESD at both the device level and the system board level, and the overall protection techniques. Finally, the course will review the advances in IC technologies that lead to future challenges for ESD development and the resulting important technology roadmap established by the ESD Association.

EOS - A Big Challenge in Today's Handling of Customer Rejects (1 Hour) GP250

Instructor: Gerold Schrittester

Handling of customer rejects has become more and more challenging over the years in view of EOS. Unlike ten years ago today most customers are asking for an EOS statement containing a conclusive and comprehensive explanation of the failure scenario that has finally resulted in an "EOS-like" damage and this EOS statement has to be discussed on much higher technical level. On the other hand still today there is not much awareness on the customer side that most "EOS-like" failure signatures do not allow a comprehensive conclusion to the origin of EOS and so the final root cause cannot be evaluated without customer's support. But in order to be prepared to conduct a successful root cause analysis together with customer the supplier is committed to build up an EOS knowledge base for both internal and external needs. The seminar should deliver insight in today's handling of customer rejects in terms of EOS and all the background that is necessary to be successful in that important topic – complemented with a few demonstrative examples.

EOS: A New Focus (1 Hour 30 minutes)

Instructor: Terry Welsher

Electrical Overstress (EOS) accounts for most of the electrical failures of devices that occur in factories and in the field. One EOS root cause, ESD, has received much attention in technical literature, standards bodies and educational workshops and tutorials. It has been approached in a systematic manner which has resulted in relatively successful practices for design of robust devices and control procedures for the factory. However, the same cannot be said for the effects of the broader categories of electrical stresses that can be the root cause of electrical overstress. These other root causes (over-voltage, over-current, over-power), when grouped together, are more prevalent causes of failure than ESD by a wide margin because of the lack of a coherent design and mitigation strategy. One of the main reasons for this is that EOS root causes are widely varied and very application dependent. As a result, no simple broad models for EOS have emerged comparable to HBM and CDM for ESD. Common device design practices have not been developed to the same extent, system level approaches tend to be ad hoc and responsibility for controlling potential sources in manufacturing tends to be diffused or non-existent. In this webinar, we review the current status of work on EOS. This will include recent significant reports in the technical literature, work of standards and industry groups and some recent interesting case histories. We will also explore the definitions of EOS and some related terms and attempt to clarify some common ways these terms are misused in literature and in failure analysis reports. "Rethinking" how we talk about EOS will help Failure Analysis, Design and Manufacturing work together to reduce EOS-induced failures (including ESD).

ESD from Basics to Advanced Protection Design (1 Hour) DD110

Instructor: Charvaka Duvvury

Certification: DD

This tutorial addresses important issues in the design of IC protection circuits built with advanced deep sub-micron CMOS technologies, including silicon-on-insulator (SOI) and high voltage MOSFETs. The tutorial will present fundamental aspects of ESD protection design such as basic NMOS and SCR concepts, as well as gate-biased and substrate driven NMOS protection concepts. Protection design methods to meet the human body model (HBM), machine model (MM), and charged device model (CDM) will be presented. Other topics to be covered include BiCMOS protection circuits, mixed voltage protection, and compatibility to latch-up. Specific design examples will be presented to assist in understanding the methods for design synthesis. This tutorial is useful for design, device, process, product, failure analysis, and reliability engineers and will assist those attending other design related tutorials. Attendees should have a minimum knowledge of MOS device operation in integrated circuits.

ESD Fundamentals I for Stress Testing (1 Hour) DT140

Instructor: Terry Welsher

Certification: DT

This tutorial is part 1 of a condensed version of the ESD Basics for the Program Manager tailored for technicians and engineers who direct or perform ESD stress testing at the device and system level. This tutorial provides the foundational material for understanding electrostatics and ESD along with their role in the manufacturing and handling of ESD sensitive devices. The fundamental properties of charge, electric fields, voltage, capacitance, and current are discussed with a view towards understanding key electrostatic phenomena and electrical processes; these include charge generation and decay, material properties, and induction. An overview of device failure mechanisms is presented, including how these models impact ESD control programs.

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ESD Fundamentals II for Stress Testing (1 Hour) DT141

Instructor: Terry Welscher

Certification: DT

This tutorial is part 2 of a condensed version of the ESD Basics for the Program Manager tailored for technicians and engineers who direct or perform ESD stress testing at the device and system level. This tutorial provides the foundational material for understanding electrostatics and ESD along with their role in the manufacturing and handling of ESD sensitive devices. The fundamental properties of charge, electric fields, voltage, capacitance, and current are discussed with a view towards understanding key electrostatic phenomena and electrical processes; these include charge generation and decay, material properties, and induction. An overview of device failure mechanisms is presented, including how these models impact ESD control programs.

ESD Problem Solving (1 Hour) GP331

Instructor: John Kinnear

It's Friday at 3:00 and your quality manager calls you, "We are having ESD failures". Now what do you do? Go out and audit your line? This online course will outline the steps that you should take to examine your process before you audit your line or even leave your office. A systematic approach will be explained on the logical steps to take for ESD troubleshooting. Only after such an analysis should you go on the line for measurements or assessments.

ESD Protection and I/O Design (3 Hour) DD201

Instructor: Michael Stockinger

This tutorial is intended to provide the attendees with the tools to take a device and circuit level understanding of ESD protection methods and implement them effectively in I/O designs for CMOS bulk technologies. Beginning with a review of common ESD protection strategies, this course will focus more directly on how to build ESD-robust I/O cells and how to integrate them on a full chip. The tutorial will cover various types of I/O pads including analog, RF and digital pads. Different types of ESD protection strategies and their usage in I/O pad cells will be described, for example rail clamp, self-contained, and SCR based protection schemes. This course will also discuss the decisions and challenges which ESD and I/O designers typically face when designing I/O pads. More complex ESD solutions will also be described such as stacked rail clamps, ghost rails, and protecting signals that can swing below ground or above the supply. Finally, this tutorial will touch on various supply schemes including multiple power domains and isolated grounding schemes. It will end with discussing pad ring construction aspects for both wire-bond and flip-chip packages.

ESD Standards Overview for the Program Manager (3 Hour) FC210

Instructor: David E Swenson

Certification: PrM

Standards provide the foundation for building an ESD Control Program. Many of the individual tutorials within the Program Manager Certification curriculum discuss specific Standards, Standard Test Methods and other standards related documents in depth. This Standards Tutorial provides an overview of all the ESD Association and other relevant industry and military Standards, grouped into common test types based on measurement probe and test instruments. A common methodology is used in this tutorial to cover the requirements, applications and specifications for each Standard and Standard Test Method. This course helps prepare students that will write the ESDA Program Manager exam.

Summary:

An overview of all the ESDA standards and related documents used in establishing an ESD control program and prepare the student for the ESDA Program Manager exam.

ESD Test Simplification with Approved Sampling Methods in HBM D-E (1 Hour) DT220

Instructor: Charvaka Duvvury

Certification: DT

Advances in semiconductor technology development have enabled significantly more complex integrated circuits (IC). This complexity has driven an increased number of pins on an IC package. These higher pin count IC packages have led to a significantly higher ESD qualification cost and complexity. However, many designs often have a large number of common or "cloned" IOs which enables the possibility of using statistical sampling schemes to help improve ESD qualification in an efficient manner without reducing the overall quality of the stress test method. This tutorial will discuss the details behind the changes that are being made to the joint ANSI/ESDA/ JEDEC JS-001-2012 HBM Test Method, including the definition of cloned IOs, the procedure for sampled testing of cloned IOs and a clear statistical justification behind these changes. The tutorial will conclude with a discussion of possible future opportunities in both HBM and CDM test methods for even further improvements in using statistical sampling techniques.

Essentials for Controlling the ESD Work Area (1 Hour) DT143

Instructor: Ginger Hansel

Certification: DT

This tutorial focuses on the basic components of an ESD controlled work area and how to verify the correct operation of each component. Most ESD protected Areas (EPA) include grounded workstations (special mats or table tops) and personnel grounding techniques (wrist straps, constant monitors, heel grounders, footwear, conductive flooring and dissipative chairs). In addition, the proper use and testing of smocks and ionization will be covered.

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Fundamentals of Failure Analysis (1 Hour) DT142

Instructor: Jim Vinson

Certification: DT

Failure analysis is the diagnostic tool of the semiconductor industry. It is the semiconductor equivalent of forensic science. Failure analysis unravels the mystery behind how and why a part failed, determining the root cause and corrective actions needed to prevent future failures. This tutorial is targeted toward people doing stress testing on a daily basis where failures are generated and need to be analyzed to determine what failed and how to improve a part's robustness. The focus will be on failure analysis methods and tools use to analyze failures resulting from ESD, TLP, or latchup related stressing but will be applicable for wearout as well as infant mortality related failures as well. The tutorial will cover the 5 basic steps necessary to perform a failure analysis: 1) Information Gathering, 2) Failure Verification, 3) Failure Site Localization, 4) Root Cause Investigation, and 5) Corrective Action.

Fundamentals of System Level Testing (1 Hour) DT130

Instructor: Mike Hopkins

Certification: DT

This tutorial provides an understanding of how testing done at the system level is essential to understanding the stress that will be applied to a device installed in the final product. This tutorial will cover the various system level testing standards including how the tests are performed and evaluated. Guidance is provided for applying these tests at the device level. Test results will be discussed and differences between hard and soft failures examined. In addition, a brief overview of tools available for root cause analysis at the system level will be examined.

Grounding in an Electrostatic Protected Area (1 Hour) FC231

Instructor: David E. Swenson

Grounding is perhaps the single most important technical aspect in establishing an electrostatic protected area. The ESD Association grounding standard ANSI/ESD S6.1 provides potential users with specifications, guidance and suggestions for implementing a grounding/bonding system suitable for nearly any imaginable application. This information is not found anywhere else in industry literature.

This web-based training session will include answers to the following questions:

- What grounding method is appropriate for a work area?
- What measurements are needed?
- Are there any new terms or definitions?
- What are the proper ways to ground personnel in the workplace?

Grounding in an Electrostatic Protected Area (1 Hour) Chinese (1 Hour) FC231

HBM Testing Essentials (1 Hour) DT100

Instructor: Brett Carn

Certification: DT

This tutorial addresses the details of Human Body Model (HBM) qualification testing. This course will help in interpretation of the HBM joint standard JEDEC/ANSI/ESD JS-001 and will include the following details: Waveform verification, understanding of Table 2A (minimum required set of pin combinations) and Table 2B (legacy pin combinations), pin categorization and pin grouping and I/O pin sampling. Stress plan details will be discussed including efficient testing (reduction in pin count) and some debugging options.

High Speed Digital Oscilloscope Fundamentals (1 Hour) DT211

Instructor: Marcos Hernandez

Certification: DT

This tutorial reviews the basic characteristics of oscilloscopes, general use of modern oscilloscopes and their specification as they relate to ESD measurements. Examples of measurements capturing waveforms and analysis on HBM, MM, HMM, CDM, and TLP waveforms will be presented. The basic specifications of a typical oscilloscope and their implications for accuracy on ESD measurements will be reviewed. Topics include sampling rate along with analog and digital bandwidth considerations.

Highlights and Key Concepts of Footwear/Flooring Standards (1 Hour) FC181

Instructor: Kevin Duncan

Footwear/Flooring Systems can play a major role in a successful ESD Control Program. How do you properly select and implement an ESD Footwear/Flooring System? This course will provide an overview of the concepts and Standards used for product qualification of footwear and flooring, as well as compliance verification of a Footwear/Flooring System. This course will focus on the Footwear/Flooring Standards and Standard Test Methods related to selecting and implementing a Footwear/Flooring System for use an ANSI/ESD S20.20 Control Program.

Highlights and Key Concepts of Footwear/Flooring Standards Korean (1 Hour) FC181

Highlights and Key Concepts of Footwear/Flooring Standards THAI (1 Hour) FC181

HMM – System Level Testing of Components D-E (1 Hour) DT131

Instructor: Mirko Scholz

Certification: DT

This tutorial will explain in detail the intent of the HMM standard test method. The tutorial starts with the hurdles of testing components to the IEC 61000-4-2 standard. The scope and purpose of the HMM standard test method will be discussed. The waveform used in this test and its critical specifications are presented along with the qualified equipment used to deliver the waveform. Three test configurations are introduced to address equipment specifics and recommending grounding. The tutorial will also provide some data to show the measurement variability that this test method has.

Integrated Circuit ESD Fundamentals (3 Hour) DD103

Instructors: Alan Righter, Warren Anderson

This three hour tutorial is focused on integrated circuit ESD fundamentals, and is targeted for two audiences: for the IC circuit designer who needs knowledge of how ESD can affect IC design, test, handling and system use; and those engineers wishing to be introduced to IC ESD, as a primer to further study. The tutorial covers the following topics:

- ESD Definitions
- Overview of the ESD Threat and ESD Controlled Workspaces
- ESD Stress Models and Standards
- Introduction to Transmission Line Pulse (TLP) ESD Testing
- ESD Design Window
- ESD Protection Network Design
- Power Clamp ESD Design and Tradeoffs
- Input Protection ESD Design
- Output Drivers ESD Design
- Switches (Transmission Gates) ESD Design
- RF ESD Protection
- IC ESD - Integration Issues
- CDM Protection Guidelines
- ESD Design Verification
- ESD Debug and Diagnosis

Integrated ESD Device and Board Level Design Part 1 (2 Hour) DD340

Instructors

part1: David Pommerenke, University of Missouri-Rolla

part2: Harald Gossner, Intel Mobile Communications

Efficient ESD design for system level ESD can only be achieved if board and device level protection circuitry coincide. The purpose of this tutorial is to develop an understanding of board/ IC interaction under IEC 61000-4-2 testing conditions and to discuss useful design strategies supported by appropriate tools. This is meant to be beneficial both for ESD engineers of ICs and board designers responsible for EMC/ESD compliant design of the system. While it has clearly been pointed out that even elevated IC level HBM targets are insufficient for achieving the required IEC 61000-4-2 ESD level, more awareness has to be developed for the detailed turn-on and clamping behavior of IC level and board level ESD protection components. High current characterization of board protection and IO circuit by TLP is a first step. This enables the board designer to assess the behavior of IC pins and select appropriate board protection elements. The design optimization should be based on high current models of board components and IC IOs and the numerical simulation of the protection network under ESD conditions. Finally, various test methods are available to evaluate the efficiency of implemented protection on board level quantitatively

Ionization Issues and Answers for the Program Manager (3 Hour) FC120

Instructor: Arnold Steinman

Certification: PrM

The primary method of static charge control is direct connection to ground for conductors, static dissipative materials, and personnel. But a complete static control program must also deal with isolated conductors, insulating materials, and moving personnel that cannot be grounded. Air ionization can neutralize the charge on insulated and isolated objects. It does this by charging the molecules of the gases in the surrounding air. Whatever charge is present on objects in the work area, it will be neutralized by attracting opposite polarity charges from the air. This webinar will present the information needed to use ionizers to solve problems caused by static charge. It is a basic course on ionizers, providing an introduction to their use, as well as advanced application information.

NOTE: Taking all three parts of this online Ionization class will fill the requirement for the full length tutorial that is part of the ESDA Program Manager Certification curriculum. Details on the Professional Certification Programs offered by ESDA are on our website at www.esda.org/certification.html.

Setting the Global Standards for Static Control!

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Latch-up Fundamentals (1 Hour) DD112

Instructor: Steve Voldman

Certification: DD

Latch-up continues to be of interest today in advanced CMOS, mixed signal (MS) CMOS, RF CMOS, BiCMOS and smart power technologies. Those attending this course will understand the fundamentals of CMOS latch-up. The course will focus on theory, test structures, application, experimental results, simulation and CAD design systems. Those attending will also understand the impact of design, semiconductor process and circuits on CMOS latch-up.

Latchup Testing and Troubleshooting (1 Hour) DT201

Instructor: Marty Johnson

Certification: DT

This tutorial focuses on latch-up testing and troubleshooting. Latch-up is primarily seen in CMOS and BiCMOS technologies but can be present in bipolar technologies. Resistance to latch-up is generally characterized during process development and design rules are implemented at device circuit block layout. Design checks for latch-up are often implemented but latch-up immunity is still mainly guaranteed by testing. This tutorial will help the student to understand the issues related to latch-up, ways to prevent it and methods used for verifying latch-up resistance in products.

On-Chip Protection in RF Technologies (1 Hour) DD102

Instructor: Steve Voldman

Certification: DD

In this tutorial, electrostatic discharge (ESD) protection in both MOSFET- and bipolar-based radio frequency (RF) technologies is discussed. It covers ESD protection in RF CMOS, BiCMOS silicon germanium, gallium arsenide, and RF silicon-on-insulator (SOI). The tutorial will focus on how RF ESD design is distinct from digital CMOS ESD design. This tutorial will focus on device physics, technology, ESD layout design, ESD circuits, and design systems. It will present methods for co-synthesizing ESD networks for RF applications. The tutorial will provide examples of RF testing methodologies for ESD qualification of components and systems. HBM, MM, and TLP measurements of RF technologies will be provided. The tutorial will provide ESD input networks, differential pair networks, and ESD power clamps used in both RF CMOS and in RF BiCMOS technologies.

Overview on Efficient and Reliable System-Level ESD (1 Hour) GP330

Instructor: Mirko Scholz

The ongoing integration of system functionality in ICs requires that IC pins comply with system-level ESD specifications. Often without knowing the final application, component-level ESD designers need to provide designs which are also robust to system-level ESD stress. In contrary, system-level ESD designer usually have no access to information about the component-level ESD protection design. To overcome this situation, the system-efficient ESD design (SEED) has been proposed. This online seminar introduces and evaluates two main system-level design methodologies: datasheet-based design and SEED (System-efficient ESD design). Different examples illustrate which data is used as design input and what are the limitations of each methodology. It is shown how component-level ESD testing and transient simulations (SPICE and mixed-mode) enable an efficient and reliable system-level ESD protection design.

Packaging Principles for the PrM (3 Hour) FC200

Instructor: David Swenson

Certification: PrM

To provide clear-cut information on what type of controlled packaging should be used in any situation, EOS/ESD Association, Inc. released a comprehensive revision of the obsolete industry standard EIA 541-1988. The newer document, ANSI/ESD S541, is the focus of this inclusive session. It provides information and guidance, as well as material specifications, to assist in the design and implementation of a packaging plan for use within an ANSI/ESD S20.20 based ESD control program. Current and newly released test method standards suitable for packaging material evaluation will be described. Course credit applies to the ESD program manager certification curriculum. Previous attendance at the "FC100: ESD Basics" and "FC101: How To's" tutorials are highly recommended.

Practical Aspects of Latch-Up for Low Voltage CMOS: Design Rules, Layout Floor Planning, and Test (1 Hour) DD222

Instructor: Scott Ruth

The idea of this tutorial would be to tackle the practical aspects of designing and testing for latch-up robustness. From a design perspective, layout floor-planning, design rules, and EDA checks will be covered. From a test perspective, standard DC latch-up testing as well as transient latch-up testing (including system-level ESD, cable discharge, and the evolving transient latch-up standard) will be covered. Finally, real world latch-up failures and diagnoses will be presented.

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Susceptibility Testing of Devices and Systems (1 Hour) FC/DD132

Instructor: Michael Hopkins

There is a disconnect in the EMC (Electro Magnetic Compatibility) world between system manufacturers testing systems for upset and device manufacturers testing devices for failure. Some system level manufacturers are pushing device manufacturers to test semiconductor devices using system level compliance standards – specifically, IEC 61000-4-2 for ESD (Electrostatic Discharge). Product manufacturers would like to believe that if devices are qualified to IEC standard(s); finished products will likewise be qualified. Unfortunately, there is a fundamental difference between system level and device level testing; fortunately however, this difference can be bridged using new susceptibility scanning techniques on the board or device. Until now, EMC and ESD susceptibility testing at the device level has not been done. In this course, we will cover scanning methods (using a magnetic field noise source and probe) that allow identification of susceptible devices in a system, sensitive areas/pins of devices and associated circuitry.

System Level for the Program Manager (3 Hour) FC140

Presenter: John Kinnear

Certification: PrM

This tutorial is intended to help those tasked with testing products to IEC and other system level ESD standards by providing detailed information on IEC 61000-4-2, the most widely used standard, and highlighting the harmonization and differences among IEC, ANSI, Telcordia, and some automotive ESD standards. We will answer common questions regarding test set-ups, test points, and procedures, and address key issues, including: 1) Differences between “verification” and “calibration” and when is each required; the influence of ESDA WG14 technical report (TR) on IEC and how it affects the calibration and verification procedures. 2) Test set-up requirements, the test environment, ground connections, and return paths and ground plane effects. 3) Testing procedures with demonstration on actual products, how the tester affects test results, and problems with test result variations due to simulator influences. 4) What points need to be tested and why, guidance on determining “operator accessible” points and ports, exempted points and ports, and what to do around connectors and connector pins. 5) ANSI and other ESD standards, the drive toward harmonization with IEC, why standards will probably never be the same as IEC, and the scope of different standards. This system level ESD tutorial will cover several facets of ESD as applied to electronic systems.

TCAD Fundamentals (1 Hour) DD117

Presenter: Kai Esmark

TCAD (technology computer aided design) tools have become an indispensable utensil for the semiconductor industry. The possibilities to analyze, predict and optimize a certain semiconductor device behavior through modeling semiconductor fabrication (Process TCAD) and semiconductor device operation (Device TCAD) are countless. This includes the area for ESD and Latch-up development, as early access to fundamental device parameters under very high current density and high temperature transients is the key to overcome the conceptual problem of concurrent engineering for ESD engineers.

TCAD Methodologies for Industrial ESD Design (1 Hour) DD205

Presenter: Vladislav Vashchenko

This seminar provides a comprehensive overview of the TCAD methodologies and best practices for industrial ESD design. Both the generic simulation workflow review and the classification of the most representative cases are covered. The advanced capability of mixed-mode simulation approach with device, circuit and process parameterization is demonstrated. Fabless and fab-light industry trends are addressed by overcoming the critical requirement of the well calibrated process simulation flow. The overall goal of the seminar is to add a new dimension to the standard R&D methodology and make it directly useful to a broad audience of ESD device, circuit and application engineers rather than corporate TCAD experts.

TLP Fundamentals – Understanding the Equipment Options (1 Hour) DD210

Instructor: Evan Grund

Certification: DT

This tutorial will explain what Transmission Line Pulsing (TLP) is and how it can be used for ESD design and development. Taking accurate TLP measurements is important thus how TLP systems make measurements and produce IV plots will be reviewed. The IV plots provide very valuable device parameters that are key to understanding the DUT being stressed. The tutorial will also explain the parameters that can be extracted from those IV curves. Finally typical equipment used in TLP systems will be reviewed.

Ultra-Sensitivity Trends and CDM (1 Hour) GP241

Instructor: Ted Dangelmayer

The electronics industry faces a double challenge: increasing use of ultra-sensitive devices and lack of experience with the Charge Device Model (CDM). This class will give you the background to understand the challenges and prepare to meet them. Case studies will illustrate how CDM failures can persist even with a robust HBM program in place. A series of photographs of common CDM issues in manufacturing will enable students to visualize how to implement CDM controls. A brief summary of the work by the Industry Council on ESD Target Levels will be included.

Ultra-sensitive (Class 0) Devices: ESD Controls and Auditing Measurements (3 Hours) FC361

Instructor: Terry Welsher, Dangelmayer Associates

Advanced ESD controls and auditing measurements for CDM & Class 0 (ultra-sensitive) devices and circuit boards are not well known and there are many technical and strategic pitfalls that must be avoided. Industry definitions (threshold levels) for Class 0 will be described and the history of their use will be reviewed. The Class 0 category is broken down into sub-categories of increasing risk. Students will learn how to make valid measurements, avoid common pitfalls, and how to use this data to successfully handle Class 0 sensitivities. Advanced measurements will be described including event detection and high speed current measurements. Students will learn when each measurement type is useful. Compelling case studies will illustrate these techniques and the success they produce.

ESD Control procedures for Class 0 manufacturing require customization, attention to detail and a full understanding of the technology. Thus, each company will need to develop a Class 0 ESD subject matter expert (SME) to ensure the correct and cost effective counter measures are taken. SOPs (special operating procedures) developed by SMEs will be discussed that have proven to virtually eliminate Class 0 failures.

This tutorial will be highly interactive with live demonstrations, in-plant photographs, and video clips. Students will be encouraged to ask questions and actively participate in the discussions. References to technical literature on ultra-sensitive devices will be included.

Use of the Digital Sampling Oscilloscope for ESD Measurements (3 Hours) FC/DD122

Instructor: Larry Levit

The digital sampling oscilloscope (DSO) finds application in measuring waveforms that occur infrequently or only once. Its sophisticated calculation and display capabilities give it utility for factory ESD, as well as, its role in monitoring ESD immunity waveforms for both component and system level ESD. Understanding instrument performance issues is important for proper use. DSO bandwidth and the sampling rate are often used interchangeably, although they serve completely different purposes. The bandwidth, sampling rate and memory depth of the instrument must be specified for the intended application. DSOs also have display modes which can hide undersampling artifacts and lead to incorrect conclusions. Selecting the appropriate display algorithm is important for both cosmetic purposes and to achieve correct results from the instrument. Also important for the proper use of any oscilloscope are selection of the input impedance and the setup of the trigger. For a DSO, the pretrigger value must also be set. In some cases equivalent time sampling can be used but in most ESD measurements, single shot acquisition is required. Finally, for ESD applications on the factory floor, there are a variety of probes that are used. These include, wide bandwidth current probes, clamp on current probes, single ended and differential voltage probes, as well as, high frequency antennas.

VF-TLP, An Introduction to Capabilities and Applications (1 Hour) DT212

Instructor: Mirko Scholz

Certification: DT

VF-TLP stands for Very Fast Transmission Line Pulsing. Standard TLP uses typically 100 ns long pulses. It allows the device characterization in the HBM time domain. VF-TLP uses pulses with a duration of a few nanoseconds and faster rise times than standard TLP. It allows the device characterization and (transient) voltage and current measurement in the CDM time domain. This tutorial explains the VF-TLP measurement setups, equipment options and how the extracted data is interpreted. Several examples explained how the VF-TLP setup parasitic are de-embedded and applied to the obtained "raw" measurement data. The goal of the tutorial is to enable the operator to deliver high quality measurement data to the ESD protection designer.